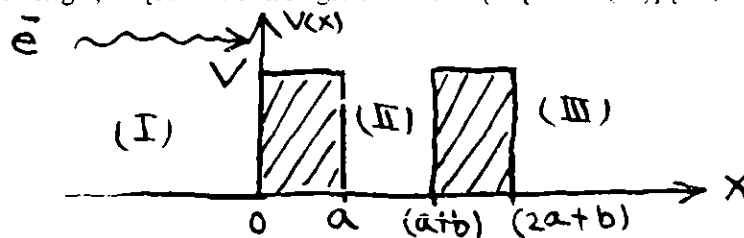


UNIVERSITY OF TORONTO  
FACULTY OF APPLIED SCIENCE AND ENGINEERING  
FINAL EXAMINATION (TYPE C), DECEMBER 18, 2001  
MMS 320

Examiner: Prof. Z.H. Lu

1. Describe the statistical function you should use to determine the probability of having an energy  $E$  at a temperature  $T$  for the following particles: (a) electrons, (b) phonons, and (c) free moving gaseous molecules.
2. Describe in your words the wave nature of electrons. Calculate the wavelength of an electron which has a kinetic energy of 4 eV.
3. Sketch the  $E$  vs  $k$  relationship for a free electron in the 1<sup>st</sup> B.Z.
4. Consider an incandescent light bulb with a tungsten filament that is 0.382 m long and has a diameter of 33  $\mu\text{m}$ . Its resistivity at room temperature is  $5.51 \times 10^{-8} \Omega \text{ m}$ . Given that the resistivity of the tungsten filament varies according to  $\rho(T) = \rho_0(T/T_0)^{1/2}$ , and the temperature of the W is 2746K at 120 V operating voltage. Estimate the power consumption (or the wattage) of the bulb at 120 V.
5. Sketch band diagrams across the following interfaces: (a) between Au and n-type Si, (b) between Ca and n-type Si. Label relevant parameters on the diagrams. (Hint: see the attached appendix for important parameters)
6. Sketch an energy band diagram across an interface between p-type Si and n-type GaAs. Label relevant parameters on the diagram.
7. Part A. Briefly describe the conduction mechanism for: (a) a conducting polymer, (b) an ionic materials, and (c) an amorphous silicon. Part B. Sketch  $P$  (polarization) vs  $E$  (external electric field) characteristics (known as hysteresis loop at room temperature) of a ferroelectric material: at (a)  $T=0\text{K}$ , (b) a temperature just below Currie temperature, and (c) above Currie temperature.
8. Describe all possible thermal energy carriers.
9. For a classical free particle with degree of motion is restricted to two dimensions. Derive (a) velocity distribution function and (b) a formula to calculate the average energy of the particle. [Hint: see appendix for definite integrals].
10. Estimate the transmission probability for an electron traveling from region I through region II to region III in the following cases; (a) the separation distance between two potential barrier  $b$  is very large. (b)  $b$  is much smaller than that of the electron wavelength. Discuss only the case where electron energy  $E$  is larger than the potential barrier height,  $V$ . [Hint: For a single barrier,  $T = \{1 + [V^2 \sin^2(ka)]/[4E(E-V)]\}^{-1}$ ]



# MMS320 Final Exam Appendix

## Electronic Properties of Some Metals

Material	Effective mass		Fermi energy, $E_F$ [eV]	Number of free electrons, $N_{eff}$ [electrons] [m <sup>3</sup> ]	Work function (photoelectric), $\phi$ [eV]	Resistivity, $\rho$ [ $\mu\Omega$ cm] at 20°C
	$\left(\frac{m^*}{m_0}\right)_{el}$	$\left(\frac{m^*}{m_0}\right)_{opt}$				
Ag		0.95	5.5	$6.1 \times 10^{28}$	4.3	1.59
Al	0.97	1.08	11.8	$16.7 \times 10^{28}$	4.1	2.65
Au		1.04	5.5	$5.65 \times 10^{28}$	4.8	2.35
Be	1.6		12.0		3.9	4.0
Ca	1.4		3.0		2.7	3.91
Cs			1.6		1.9	20.0
Cu	1.0	1.42	7.0	$6.3 \times 10^{28}$	4.5	1.67
Fe	1.2				4.7	9.71

Properties	Si	GaAs
Atoms/cm <sup>3</sup>	$5.02 \times 10^{22}$	$4.42 \times 10^{22}$
Atomic weight	28.09	144.63
Breakdown field (V/cm)	$\sim 3 \times 10^5$	$\sim 4 \times 10^5$
Crystal structure	Diamond	Zincblende
Density (g/cm <sup>3</sup> )	2.329	5.317
Dielectric constant	11.9	12.4
Effective density of states in conduction band, $N_c$ (cm <sup>-3</sup> )	$2.8 \times 10^{19}$	$4.7 \times 10^{17}$
Effective density of states in valence band, $N_v$ (cm <sup>-3</sup> )	$1.04 \times 10^{19}$	$7.0 \times 10^{18}$
Effective mass, $m^*/m_0$		
Electrons	$m_{el}^* = 0.92$	0.063
Holes	$m_{hh}^* = 0.19$ $m_{lh}^* = 0.15$ $m_{hh}^* = 0.54$	$m_{lh}^* = 0.076$ $m_{hh}^* = 0.50$
Electron affinity, $\chi$ (V)	4.05	4.07
Energy gap (eV) at 300 K	1.124	1.424
Index of refraction	3.42	3.3
Intrinsic carrier concentration (cm <sup>-3</sup> )	$1.02 \times 10^{10}$	$2.1 \times 10^6$
Intrinsic Debye length ( $\mu$ m)	41	2900
Intrinsic resistivity ( $\Omega$ -cm)	$3.16 \times 10^5$	$3.1 \times 10^8$
Lattice constant ( $\text{\AA}$ )	5.43102	5.65325
Linear coefficient of thermal expansion, $\Delta L/L\Delta T$ (°C <sup>-1</sup> )	$2.59 \times 10^{-6}$	$5.75 \times 10^{-6}$

## Some Definite Integrals

$$\int_0^{\infty} x \cdot e^{-ax} dx \equiv 1/a^2$$

$$\int_0^{\infty} e^{-ax^2} dx \equiv (\pi/4a)^{1/2}$$

$$\int_0^{\infty} x \cdot e^{-ax^2} dx \equiv 1/(2a)$$

$$\int_0^{\infty} x^2 \cdot e^{-ax^2} dx \equiv (\pi/16a^3)^{1/2}$$

$$\int_0^{\infty} x^3 \cdot e^{-ax^2} dx \equiv 1/(2a^2)$$

$$\int_0^{\infty} x^4 \cdot e^{-ax^2} dx \equiv (3/8a^2)(\pi/a)^{1/2}$$